

HF/VHF/UHF RF power N-channel MOSFETs

Features

- Gold metallization
- Excellent thermal stability
- Common source configuration, push pull
- $P_{OUT} = 350 \text{ W min.}$ with 15 db gain @ 175 MHz
- Low $R_{DS(on)}$

Description

The SD2942 is a gold metallized N-channel MOS field-effect transistor. The SD2942 offers 25% lower $R_{DS(ON)}$ than industry standard and 20% higher power saturation than ST SD2932. These characteristics make the SD2942 ideal for 50 V DC very high power applications up to 250 MHz.

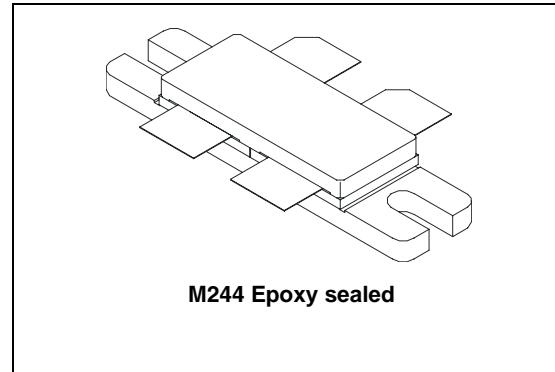


Figure 1. Pin connection

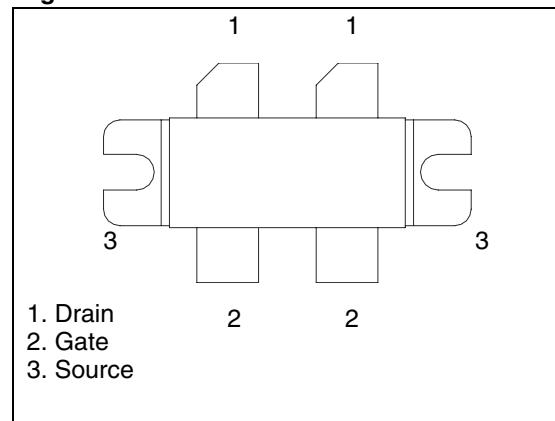


Table 1. Device summary

| Order code | Marking | Base qty. | Package | Packaging |
|------------|-----------------------|-----------|---------|-----------|
| SD2942W | SD2942 ⁽¹⁾ | 15 | M244 | Tube |

1. For more details please refer to [Chapter 7: Marking, packing and shipping specifications](#).

Content

| | | |
|----------|---|-----------|
| 1 | Electrical data | 3 |
| 1.1 | Maximum rating | 3 |
| 1.2 | Thermal data | 3 |
| 2 | Electrical characteristics | 4 |
| 3 | Impedance | 5 |
| 4 | Typical performance | 6 |
| 5 | Test circuit | 10 |
| 6 | Package mechanical data | 13 |
| 7 | Marking, packing and shipping specifications | 15 |
| 8 | Revision history | 16 |

1 Electrical data

1.1 Maximum rating

$T_{CASE} = 25^\circ C$

Table 2. Absolute maximum rating

| Symbol | Parameter | Value | Unit |
|---------------------|--|-------------|------------|
| $V_{(BR)DSS}^{(1)}$ | Drain source voltage | 130 | V |
| $V_{DGR}^{(1)}$ | Drain-gate voltage ($R_{GS} = 1M\Omega$) | 130 | V |
| V_{GS} | Gate-source voltage | ± 20 | V |
| I_D | Drain current | 40 | A |
| P_{DISS} | Power dissipation | 500 | W |
| T_J | Max. operating junction temperature | +200 | $^\circ C$ |
| T_{STG} | Storage temperature | -65 to +150 | $^\circ C$ |

1. $T_J = 150^\circ C$

1.2 Thermal data

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|------------|-------------------------------------|-------|--------------|
| R_{thJC} | Junction to case thermal resistance | 0.35 | $^\circ C/W$ |

2 Electrical characteristics

$T_{CASE} = 25^\circ\text{C}$

Table 4. Static (per section)

| Symbol | Test conditions | | Min. | Typ. | Max. | Unit |
|---------------------|-------------------------|---------------------------|---------------------|------|------|---------------|
| $V_{(BR)DSS}^{(1)}$ | $V_{GS} = 0 \text{ V}$ | $I_{DS} = 100 \text{ mA}$ | 130 | | | V |
| I_{DSS} | $V_{GS} = 0 \text{ V}$ | $V_{DS} = 50 \text{ V}$ | | | 100 | μA |
| I_{GSS} | $V_{GS} = 20 \text{ V}$ | $V_{DS} = 0 \text{ V}$ | | | 250 | nA |
| $V_{GS(Q)}$ | $V_{DS} = 10 \text{ V}$ | $I_D = 250 \text{ mA}$ | 1.5 | | 4 | V |
| $V_{DS(ON)}$ | $V_{GS} = 10 \text{ V}$ | $I_D = 10 \text{ A}$ | | | 3.0 | V |
| G_{FS} | $V_{DS} = 10 \text{ V}$ | $I_D = 5 \text{ A}$ | 5 | | | mho |
| C_{ISS} | $V_{GS} = 0 \text{ V}$ | $V_{DS} = 50 \text{ V}$ | $f = 1 \text{ MHz}$ | 415 | | pF |
| C_{OSS} | $V_{GS} = 0 \text{ V}$ | $V_{DS} = 50 \text{ V}$ | $f = 1 \text{ MHz}$ | 236 | | pF |
| C_{RSS} | $V_{GS} = 0 \text{ V}$ | $V_{DS} = 50 \text{ V}$ | $f = 1 \text{ MHz}$ | 17 | | pF |

1. $T_J = 150^\circ\text{C}$

Table 5. Dynamic

| Symbol | Test Conditions | | | Min. | Typ. | Max. | Unit |
|---------------|-------------------------|---------------------------|---------------------------|-----------------------|------|------|------|
| P_{OUT} | $V_{DD} = 50 \text{ V}$ | $I_{DQ} = 500 \text{ mA}$ | $f = 175 \text{ MHz}$ | 350 | | | W |
| G_{PS} | $V_{DD} = 50 \text{ V}$ | $I_{DQ} = 500 \text{ mA}$ | $P_{OUT} = 350 \text{ W}$ | $f = 175 \text{ MHz}$ | 15 | 17 | |
| η_b | $V_{DD} = 50 \text{ V}$ | $I_{DQ} = 500 \text{ mA}$ | $P_{OUT} = 350 \text{ W}$ | $f = 175 \text{ MHz}$ | 55 | 61 | % |
| Load mismatch | $V_{DD} = 50 \text{ V}$ | $I_{DQ} = 500 \text{ mA}$ | $P_{OUT} = 350 \text{ W}$ | $f = 175 \text{ MHz}$ | 5:1 | | VSWR |
| | all phase angles | | | | | | |

3 Impedance

Figure 2. Impedance data schematic

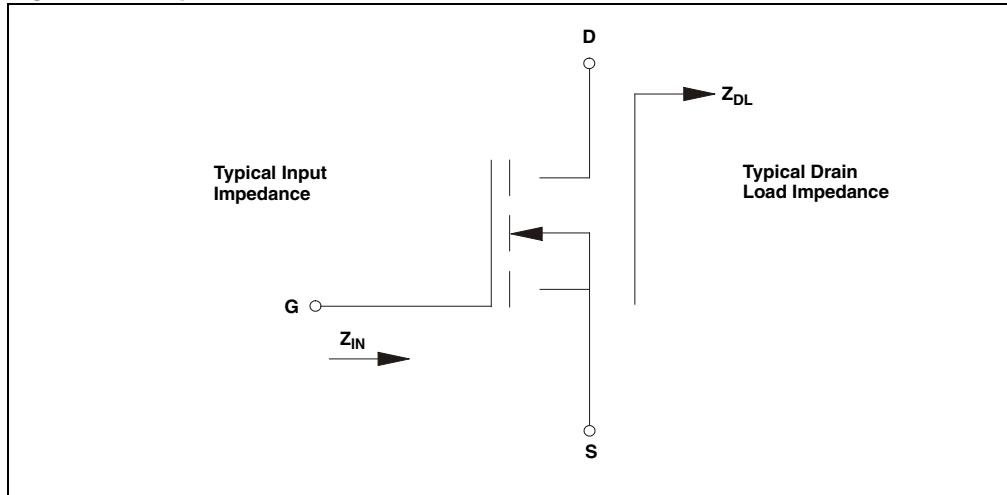


Table 6. Impedance data

| f | $Z_{IN} (\Omega)$ | $Z_{DL} (\Omega)$ |
|---------|-------------------|-------------------|
| 250 MHz | $1.3 - j 1.9$ | $1.9 + j 3.2$ |
| 230 MHz | $1.2 - j 1.8$ | $2.1 + j 3.7$ |
| 200 MHz | $1.1 - j 1.6$ | $2.7 + j 4.2$ |
| 175 MHz | $1.0 - j 1.4$ | $3.3 + j 4.8$ |
| 100 MHz | $1.8 - j 2.5$ | $7.5 + j 9$ |
| 50 MHz | $3.2 - j 4.4$ | $10 + j 12$ |

4 Typical performance

Figure 3. Capacitance vs drain voltage

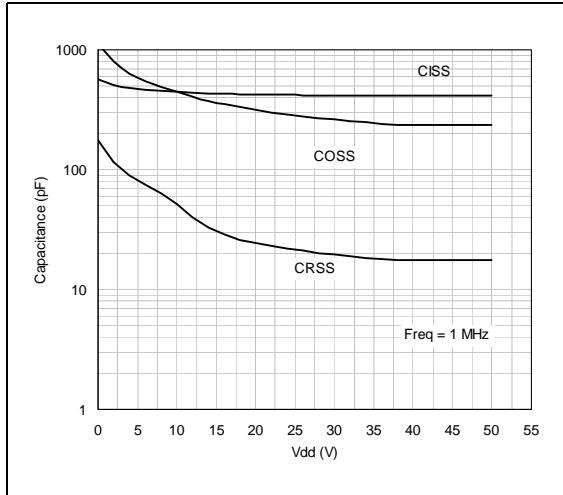


Figure 4. Drain current vs gate voltage

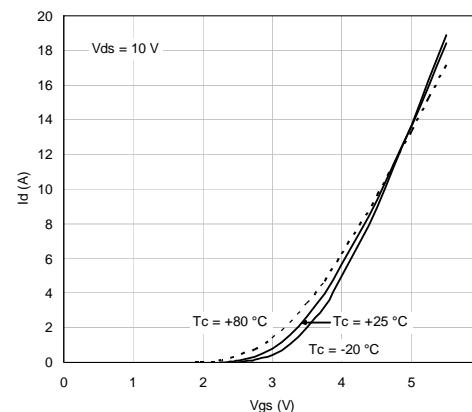


Figure 5. Gate-source voltage vs case temperature

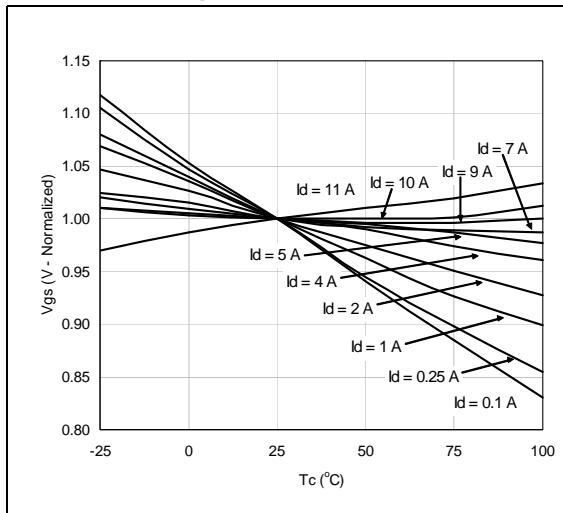


Figure 6. Power gain vs P_{OUT} and case temperature

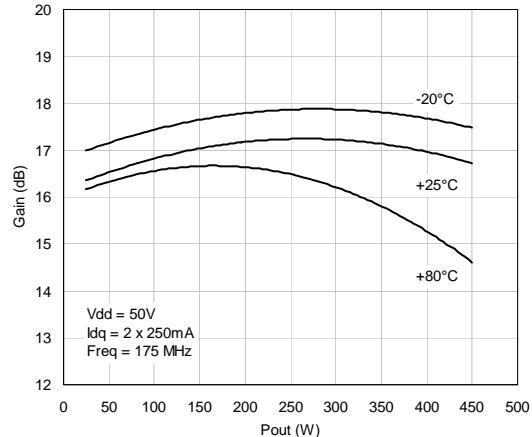


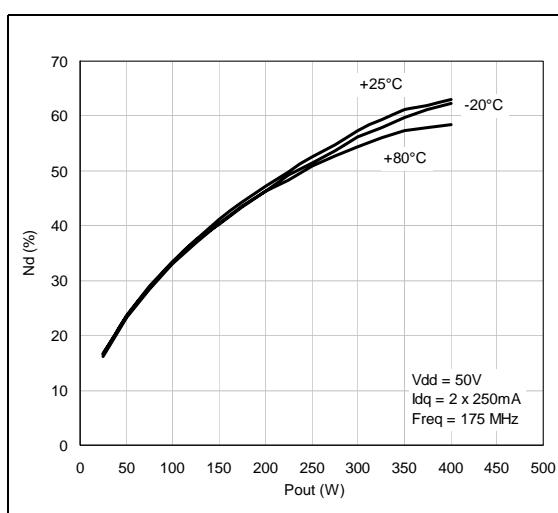
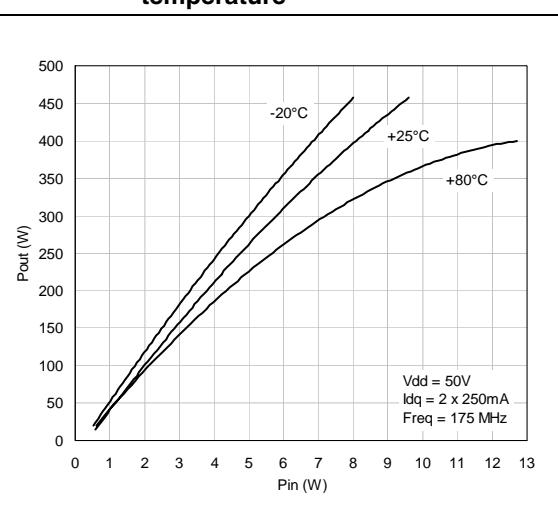
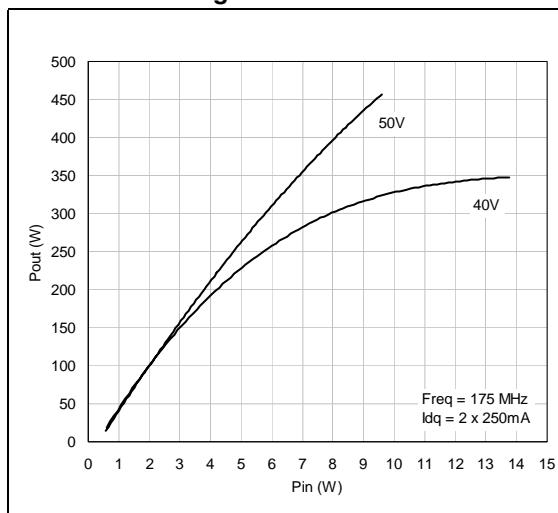
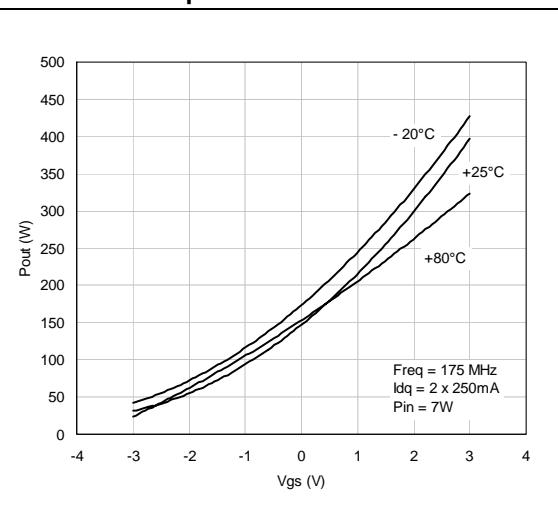
Figure 7. Efficiency vs case temperature**Figure 8. P_{OUT} vs input power and case temperature****Figure 9. P_{OUT} vs input power and drain voltage****Figure 10. P_{OUT} vs gate voltage and case temperature**

Figure 11. P_{out} vs drain voltage and input power

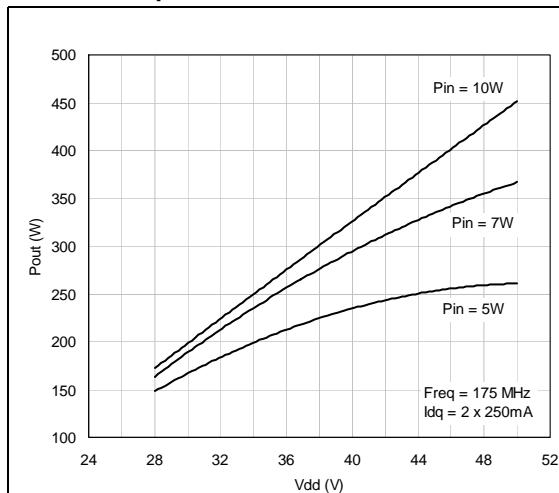


Figure 12. Maximum thermal resist vs case temperature

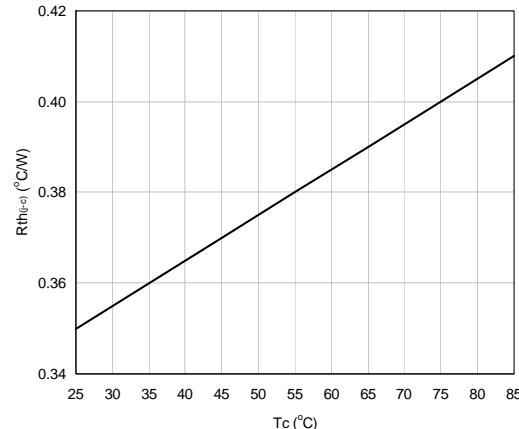


Figure 13. Maximum safe operating area

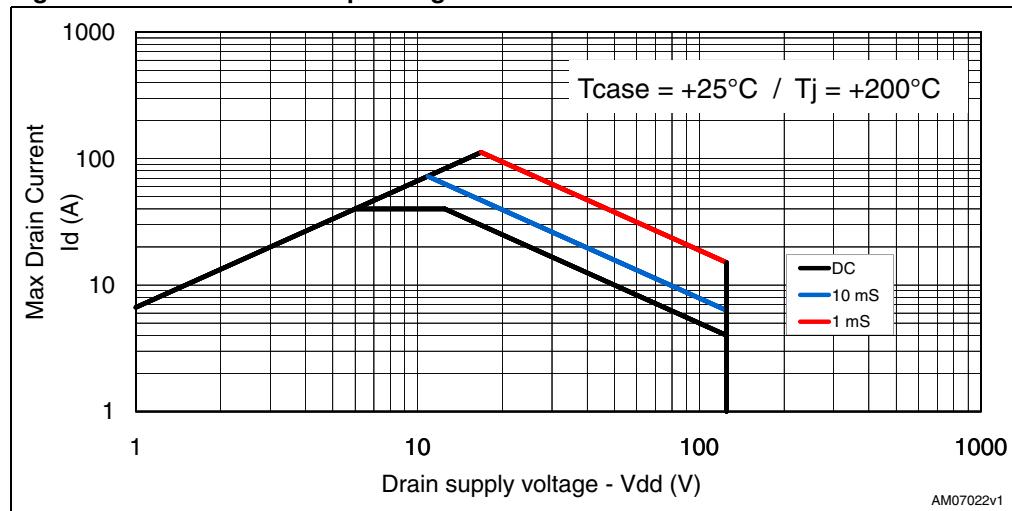
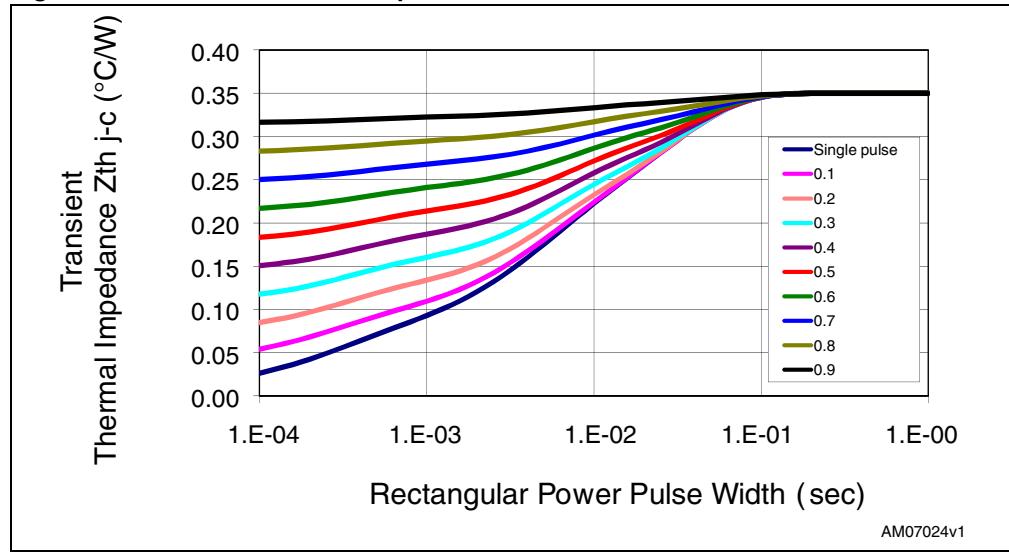
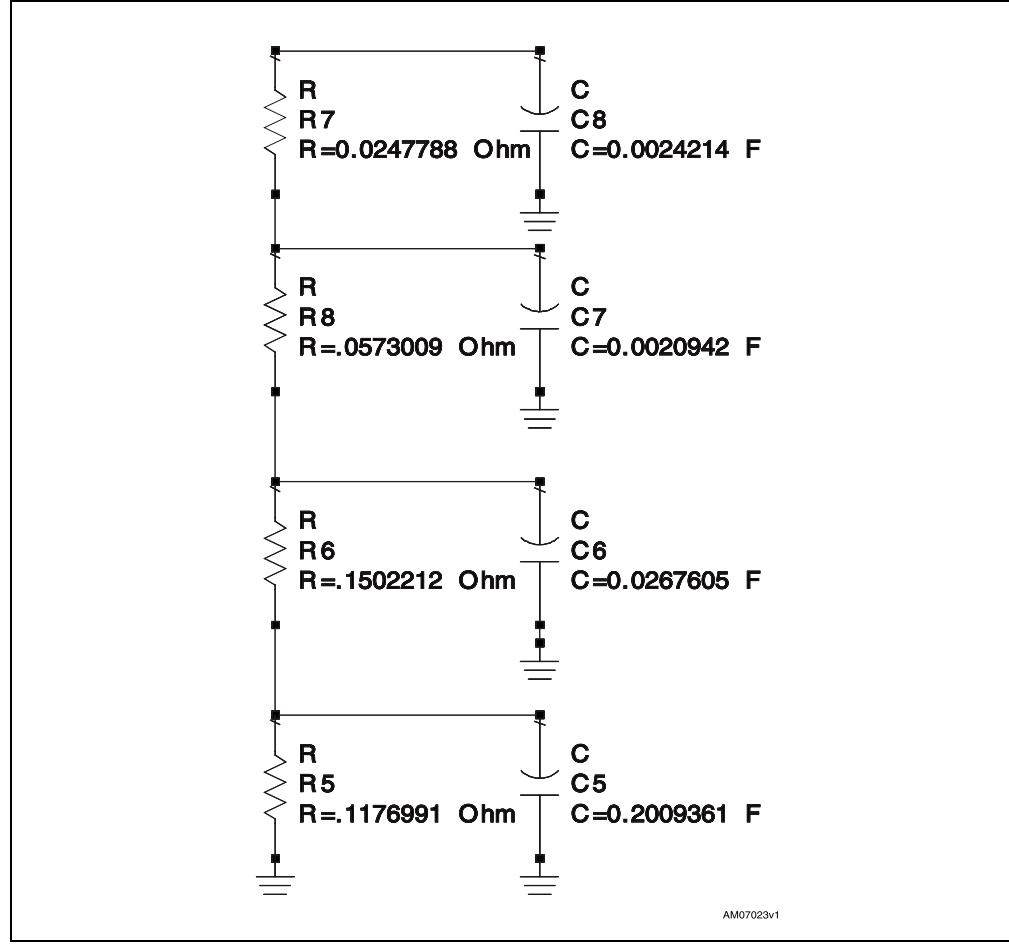
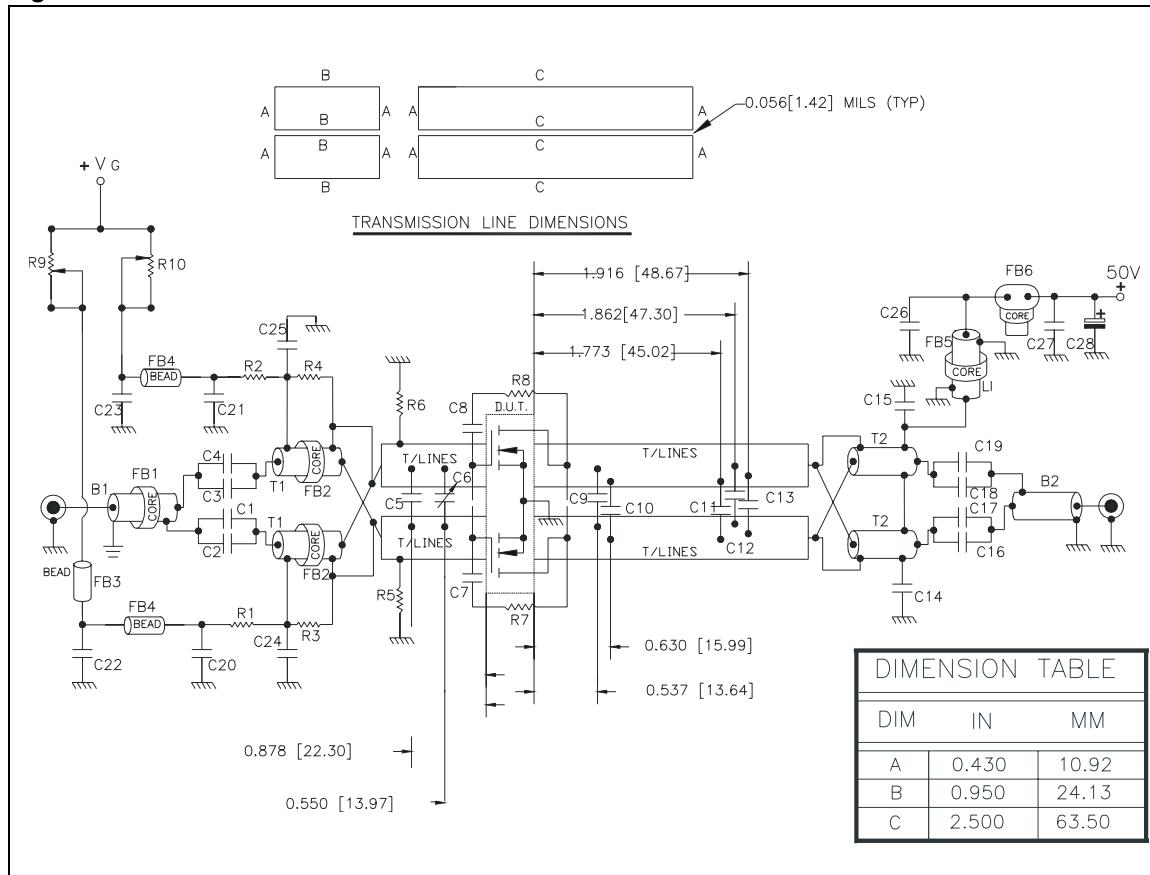


Figure 14. Transient thermal impedance**Figure 15.** Transient thermal model

5 Test circuit

Figure 16. 175 MHz test circuit schematic



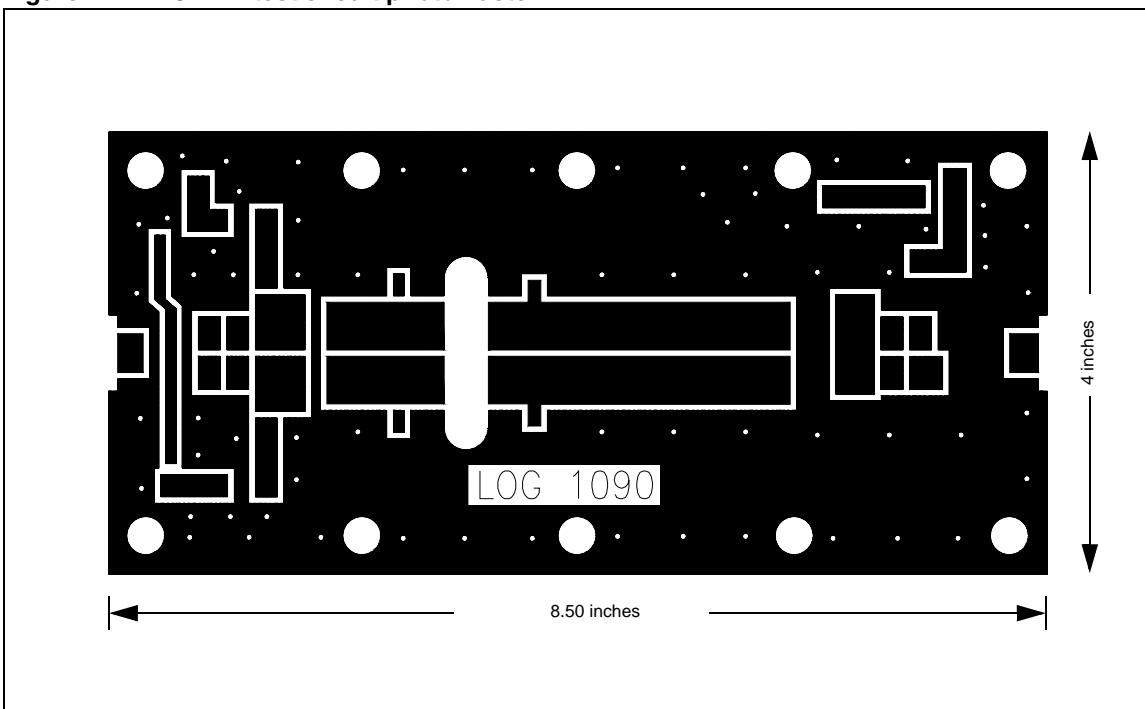
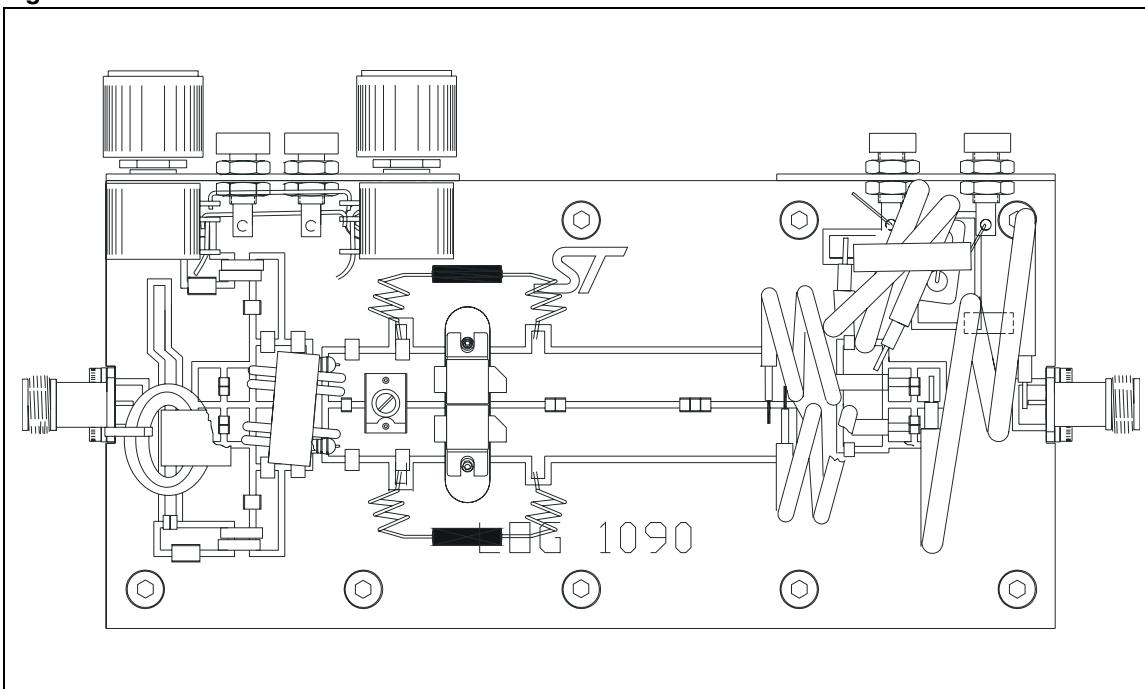
Note: 1 Dimensions at component symbols are references for component placement.

2 Gap between ground and transmission lines is + 0.002{0.05} - 0.000{0.00} Typ.

Table 7. 175 MHz test circuit component list

| Symbol | Description |
|-----------------------------|--|
| R1,R2,R5,R6 | 470 Ω 1 W, surface mount chip resistor |
| R3,R4 | 360 Ω 0.5 W, carbon comp. axial lead resistor or equivalent |
| R7,R8 | 560 Ω 2 W, resistor two turn wire air-wound axial lead resistor |
| R9,R10 | 20 KΩ 3.09 W, 10 turn wirewound precision potentiometer |
| C1,C4 | 680 pF ATC 130B surface mount ceramic chip capacitor |
| C2,C3,C7,C8,C17,C19,C20,C21 | 10000 pF ATC 200B surface mount ceramic chip capacitor |
| C5 | 75 pF ATC 100B surface mount ceramic chip capacitor |
| C6 | ST40 25 pF - 115 pF miniature variable trimmer |
| C9,C10 | 47 pF ATC 100B surface mount ceramic chip capacitor |
| C11,C12, C13 | 43 pF ATC 100B surface mount ceramic chip capacitor |
| C14,C15,C24,C25 | 1200 pF ATC 700B surface mount ceramic chip capacitor |
| C16,C18 | 470 pF ATC 700B surface mount ceramic chip capacitor |
| C22,C23 | 0.1 μF / 500 V surface mount ceramic chip capacitor |
| C26,C27 | 0.01 μF / 500 V surface mount ceramic chip capacitor |
| C28 | 10 μF / 63 aluminum electrolytic axial lead capacitor |
| B1 | 50 Ω RG316 O.D. 0.076[1.93] L = 11.80[299.72] flexible coaxial cable 4 turns through ferrite bead |
| B2 | 50 Ω RG-142B O.D. 0.165[4.19] L = 11.80[299.72] flexible coaxial cable |
| T1 | R.F. transformer 4:1, 25 Ω O.D. RG316-25 O.D. 0.080[2.03] L = 5.90[149.86] flexible coaxial cable 2 turns through ferrite bead multi-aperture core |
| T2 | R.F. transformer 1:4, 25 Ω semi-rigid coaxial cable O.D. 0.141[3.58] L = 5.90[149.86] |
| L1 | Inductor λ 1/4 wave 50 Ω O.D. 0.165[4.19] L = 11.80 [299.72] flexible coaxial cable 2 turns through ferrite bead |
| FB1,FB5 | Shield bead |
| FB2,FB6 | Multi-aperture core |
| FB3 | Multilayer ferrite chip bead (surface mount) |
| FB4 | Surface mount EMI shield bead |
| PCB | Woven glass reinforced ptfe microwave Laminate 0.06", 1 oz EDCu, both sides, εr = 2.55 |



Figure 17. 175 MHz test circuit photomaster**Figure 18.** 175 MHz test circuit

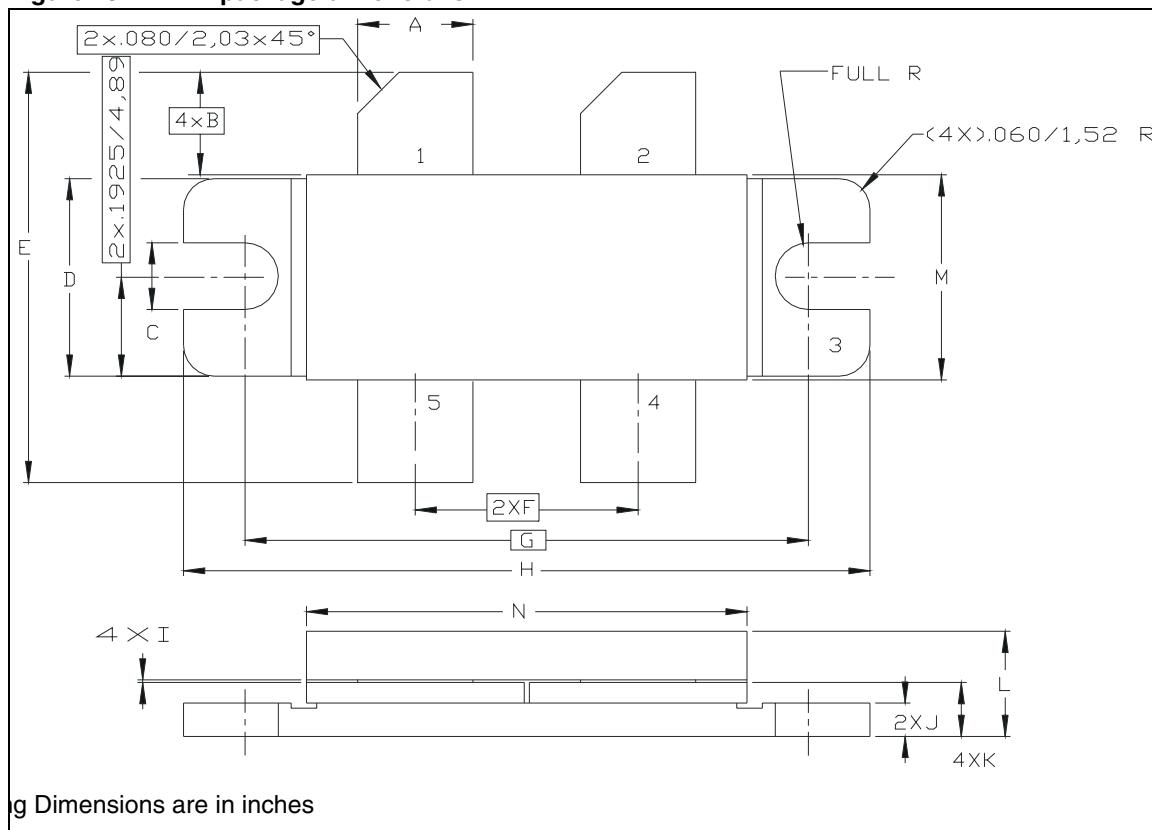
6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
ECOPACK is an ST trademark.

Table 8. M244 (.400 x .860 4/L BAL N/HERM W/FLG)

| DIM. | mm. | | | inch | | |
|------|-------|-------|-------|-------|-------|-------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 5.59 | | 5.84 | 0.220 | | 0.230 |
| B | | 5.08 | | | 0.200 | |
| C | 3.02 | | 3.28 | 0.119 | | 0.129 |
| D | 9.65 | | 9.91 | 0.380 | | 0.390 |
| E | 19.81 | | 20.82 | 0.780 | | 0.820 |
| F | 10.92 | | 11.18 | 0.430 | | 0.440 |
| G | | 27.94 | | | 1.100 | |
| H | 33.91 | | 34.16 | 1.335 | | 1.345 |
| I | 0.10 | | 0.15 | 0.004 | | 0.006 |
| J | 1.52 | | 1.78 | 0.060 | | 0.070 |
| K | 2.59 | | 2.84 | 0.102 | | 0.112 |
| L | 4.83 | | 5.84 | 0.190 | | 0.230 |
| M | 10.03 | | 10.34 | 0.395 | | 0.407 |
| N | 21.59 | | 22.10 | 0.850 | | 0.870 |



Figure 19. M244 package dimensions

7 Marking, packing and shipping specifications

Table 9. Packing and shipping specifications

| Order code | Packaging | Pcs per tray | Dry pack humidity | Lot code |
|------------|-----------|--------------|-------------------|-----------|
| SD2942W | Tube | 15 | < 10 % | Not mixed |

Figure 20. Marking layout

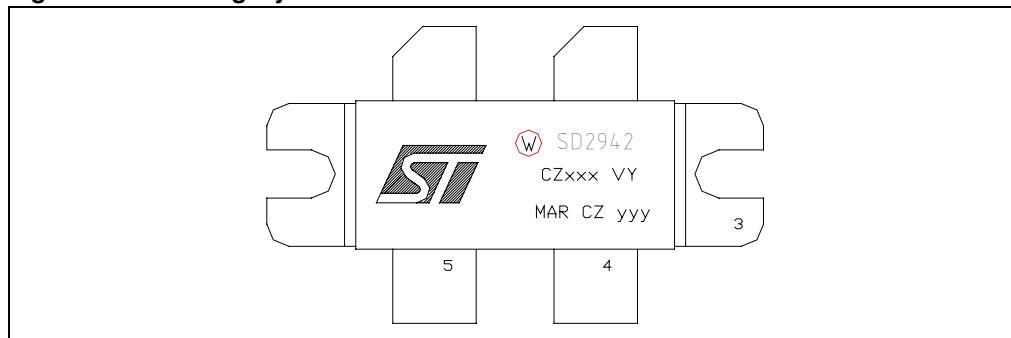


Table 10. Marking specifications

| Symbol | Description |
|--------|--------------------------------|
| W | Wafer process code |
| CZ | Assembly plant |
| xxx | Last 3 digits of diffusion lot |
| VY | Diffusion plant |
| MAR | Country of origin |
| CZ | Test and finishing plant |
| y | Assembly year |
| yy | Assembly week |

8 Revision history

Table 11. Document revision history

| Date | Revision | Changes |
|-------------|----------|---|
| 18-Oct-2005 | 1 | First Issue. |
| 04-Jan-2006 | 2 | Complete version. |
| 14-Apr-2010 | 3 | Added <i>Figure 13</i> , <i>Figure 14</i> and <i>Figure 15</i> . |
| 25-Oct-2011 | 4 | Inserted <i>Chapter 7: Marking, packing and shipping specifications</i> . |

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